General Description

The 83905 is a low skew, 1-to-6 LVCMOS / LVTTL Fanout Buffer. The low impedance LVCMOS/LVTTL outputs are designed to drive 50Ω series or parallel terminated transmission lines. The effective fanout can be increased from 6 to 12 by utilizing the ability of the outputs to drive two series terminated lines. The 83905 is characterized at full 3.3V, 2.5V, and 1.8V, mixed 3.3V/2.5V, 3.3V/1.8V and 2.5V/1.8V output operating supply mode. Guaranteed output and part-to-part skew characteristics along with the 1.8V output capabilities makes the 83905 ideal for high performance, single ended applications that also require a limited output voltage.

Features

- Six LVCMOS / LVTTL outputs
- Outputs able to drive 12 series terminated lines
- Crystal Oscillator Interface
- Crystal input frequency range: 10MHz to 40MHz
- Output skew: 80ps (maximum)
- RMS phase jitter @ 25MHz, (100Hz – 1MHz): 0.26ps (typical), \( V_{DD} = V_{DDO} = 2.5V \)
- 5V tolerant enable inputs
- Synchronous output enables
- Operating power supply modes:
  - Full 3.3V, 2.5V, 1.8V
  - Mixed 3.3V core/2.5V output operating supply
  - Mixed 3.3V core/1.8V output operating supply
  - Mixed 2.5V core/1.8V output operating supply
- 0°C to 70°C ambient operating temperature
- Lead-free (RoHS 6) packaging

Pin Assignments

- 83905
  - 20-Lead VFQFN
  - 4mm x 4mm x 0.925mm
  - package body
  - K Package
  - Top View

- 83905
  - 16-Lead SOIC, 150 Mil
  - 3.9mm x 9.9mm x 1.38mm
  - package body
  - M Package
  - Top View

- 83905
  - 16-Lead TSSOP
  - 4.4mm x 5.0mm x 0.925mm
  - package body
  - G Package
  - Top View

Offset Noise Power

<table>
<thead>
<tr>
<th>Frequency</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>100Hz</td>
<td>-129.7 dBc/Hz</td>
</tr>
<tr>
<td>1kHz</td>
<td>-144.4 dBc/Hz</td>
</tr>
<tr>
<td>10kHz</td>
<td>-147.3 dBc/Hz</td>
</tr>
<tr>
<td>100kHz</td>
<td>-157.3 dBc/Hz</td>
</tr>
</tbody>
</table>

Block Diagram
Pin Descriptions and Characteristics

Table 1. Pin Descriptions

<table>
<thead>
<tr>
<th>Name</th>
<th>Type</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>XTAL_OUT</td>
<td>Output</td>
<td>Crystal oscillator interface. XTAL_OUT is the output.</td>
</tr>
<tr>
<td>XTAL_IN</td>
<td>Input</td>
<td>Crystal oscillator interface. XTAL_IN is the input.</td>
</tr>
<tr>
<td>ENABLE1, ENABLE2</td>
<td>Input</td>
<td>Clock enable. LVCMOS/LVTTL interface levels. See Table 3.</td>
</tr>
<tr>
<td>BCLK0, BCLK1, BCLK2, BCLK3, BCLK4, BCLK5</td>
<td>Output</td>
<td>Clock outputs. LVCMOS/LVTTL interface levels.</td>
</tr>
<tr>
<td>GND</td>
<td>Power</td>
<td>Power supply ground.</td>
</tr>
<tr>
<td>V_DD</td>
<td>Power</td>
<td>Power supply pin.</td>
</tr>
<tr>
<td>V_DDO</td>
<td>Power</td>
<td>Output supply pin.</td>
</tr>
<tr>
<td>nc</td>
<td>Unused</td>
<td>No connect.</td>
</tr>
</tbody>
</table>

Table 2. Pin Characteristics

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Minimum</th>
<th>Typical</th>
<th>Maximum</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>C_IN</td>
<td>Input Capacitance</td>
<td></td>
<td>4</td>
<td></td>
<td></td>
<td>pF</td>
</tr>
<tr>
<td>C_PD</td>
<td>Power Dissipation Capacitance</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>(per output)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>V_DD = 3.465V</td>
<td>19</td>
<td>pF</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>V_DD = 2.625V</td>
<td>18</td>
<td>pF</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>V_DD = 2.0V</td>
<td>16</td>
<td>pF</td>
<td></td>
</tr>
<tr>
<td>R_OUT</td>
<td>Output Impedance</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>Ω</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>V_DD = 3.3V ± 5%</td>
<td>7</td>
<td>Ω</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>V_DD = 2.5V ± 5%</td>
<td>7</td>
<td>Ω</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>V_DD = 1.8V ± 0.2V</td>
<td>10</td>
<td>Ω</td>
<td></td>
</tr>
</tbody>
</table>

Function Table

Table 3. Clock Enable Function Table

<table>
<thead>
<tr>
<th>Control Inputs</th>
<th>Outputs</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>BCLK[0:4]</td>
</tr>
<tr>
<td>ENABLE 1</td>
<td>ENABLE2</td>
</tr>
<tr>
<td>0</td>
<td>0</td>
</tr>
<tr>
<td>0</td>
<td>1</td>
</tr>
<tr>
<td>1</td>
<td>0</td>
</tr>
<tr>
<td>1</td>
<td>1</td>
</tr>
</tbody>
</table>

Figure 1. Enable Timing Diagram
Absolute Maximum Ratings

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the DC Characteristics or AC Characteristics is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

<table>
<thead>
<tr>
<th>Item</th>
<th>Rating</th>
</tr>
</thead>
<tbody>
<tr>
<td>Supply Voltage, $V_{DD}$</td>
<td>4.6V</td>
</tr>
<tr>
<td>Inputs, $V_I$</td>
<td>-0.5V to $V_{DD}$ + 0.5V</td>
</tr>
<tr>
<td>Outputs, $V_O$</td>
<td>-0.5V to $V_{DDO}$ + 0.5V</td>
</tr>
<tr>
<td>Package Thermal Impedance, $\theta_{JA}$</td>
<td>78.8°C/W (0 mps)</td>
</tr>
<tr>
<td>16-Lead SOIC package</td>
<td>100.3°C/W (0 mps)</td>
</tr>
<tr>
<td>16-Lead TSSOP package</td>
<td>57.5°C/W (0 mps)</td>
</tr>
<tr>
<td>Storage Temperature, $T_{STG}$</td>
<td>-65°C to 150°C</td>
</tr>
</tbody>
</table>

DC Electrical Characteristics

Table 4A. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%, T_A = 0°C to 70°C

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Minimum</th>
<th>Typical</th>
<th>Maximum</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{DD}$</td>
<td>Power Supply Voltage</td>
<td></td>
<td>3.135</td>
<td>3.3</td>
<td>3.465</td>
<td>V</td>
</tr>
<tr>
<td>$V_{DDO}$</td>
<td>Output Supply Voltage</td>
<td></td>
<td>3.135</td>
<td>3.3</td>
<td>3.465</td>
<td>V</td>
</tr>
<tr>
<td>$I_{DD}$</td>
<td>Power Supply Current</td>
<td>ENABLE [1:2] = 00</td>
<td></td>
<td></td>
<td>10</td>
<td>mA</td>
</tr>
<tr>
<td>$I_{DDO}$</td>
<td>Output Supply Current</td>
<td>ENABLE [1:2] = 00</td>
<td></td>
<td></td>
<td>5</td>
<td>mA</td>
</tr>
</tbody>
</table>

Table 4B. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 2.5V \pm 5\%, T_A = 0°C to 70°C

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Minimum</th>
<th>Typical</th>
<th>Maximum</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{DD}$</td>
<td>Power Supply Voltage</td>
<td></td>
<td>2.375</td>
<td>2.5</td>
<td>2.625</td>
<td>V</td>
</tr>
<tr>
<td>$V_{DDO}$</td>
<td>Output Supply Voltage</td>
<td></td>
<td>2.375</td>
<td>2.5</td>
<td>2.625</td>
<td>V</td>
</tr>
<tr>
<td>$I_{DD}$</td>
<td>Power Supply Current</td>
<td>ENABLE [1:2] = 00</td>
<td></td>
<td></td>
<td>8</td>
<td>mA</td>
</tr>
<tr>
<td>$I_{DDO}$</td>
<td>Output Supply Current</td>
<td>ENABLE [1:2] = 00</td>
<td></td>
<td></td>
<td>4</td>
<td>mA</td>
</tr>
</tbody>
</table>

Table 4C. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 1.8V \pm 0.2V, T_A = 0°C to 70°C

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Minimum</th>
<th>Typical</th>
<th>Maximum</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{DD}$</td>
<td>Power Supply Voltage</td>
<td></td>
<td>1.6</td>
<td>1.8</td>
<td>2.0</td>
<td>V</td>
</tr>
<tr>
<td>$V_{DDO}$</td>
<td>Output Supply Voltage</td>
<td></td>
<td>1.6</td>
<td>1.8</td>
<td>2.0</td>
<td>V</td>
</tr>
<tr>
<td>$I_{DD}$</td>
<td>Power Supply Current</td>
<td>ENABLE [1:2] = 00</td>
<td></td>
<td></td>
<td>5</td>
<td>mA</td>
</tr>
<tr>
<td>$I_{DDO}$</td>
<td>Output Supply Current</td>
<td>ENABLE [1:2] = 00</td>
<td></td>
<td></td>
<td>3</td>
<td>mA</td>
</tr>
</tbody>
</table>
Table 4D. Power Supply DC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, $T_A = 0^\circ C$ to 70$^\circ C$

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Minimum</th>
<th>Typical</th>
<th>Maximum</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{DD}$</td>
<td>Power Supply Voltage</td>
<td></td>
<td>3.135</td>
<td>3.3</td>
<td>3.465</td>
<td>V</td>
</tr>
<tr>
<td>$V_{DDO}$</td>
<td>Output Supply Voltage</td>
<td></td>
<td>2.375</td>
<td>2.5</td>
<td>2.625</td>
<td>V</td>
</tr>
<tr>
<td>$I_{DD}$</td>
<td>Power Supply Current</td>
<td>ENABLE [1:2] = 00</td>
<td></td>
<td></td>
<td>10</td>
<td>mA</td>
</tr>
<tr>
<td>$I_{DDO}$</td>
<td>Output Supply Current</td>
<td>ENABLE [1:2] = 00</td>
<td></td>
<td></td>
<td>4</td>
<td>mA</td>
</tr>
</tbody>
</table>

Table 4E. Power Supply DC Characteristics, $3.3V \pm 5\%$, $V_{DDO} = 1.8V \pm 0.2V$, $T_A = 0^\circ C$ to 70$^\circ C$

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Minimum</th>
<th>Typical</th>
<th>Maximum</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{DD}$</td>
<td>Power Supply Voltage</td>
<td></td>
<td>3.135</td>
<td>3.3</td>
<td>3.465</td>
<td>V</td>
</tr>
<tr>
<td>$V_{DDO}$</td>
<td>Output Supply Voltage</td>
<td></td>
<td>1.6</td>
<td>1.8</td>
<td>2.0</td>
<td>V</td>
</tr>
<tr>
<td>$I_{DD}$</td>
<td>Power Supply Current</td>
<td>ENABLE [1:2] = 00</td>
<td></td>
<td></td>
<td>10</td>
<td>mA</td>
</tr>
<tr>
<td>$I_{DDO}$</td>
<td>Output Supply Current</td>
<td>ENABLE [1:2] = 00</td>
<td></td>
<td></td>
<td>3</td>
<td>mA</td>
</tr>
</tbody>
</table>

Table 4F. Power Supply DC Characteristics, $V_{DD} = 2.5V \pm 5\%$, $V_{DDO} = 1.8V \pm 0.2V$, $T_A = 0^\circ C$ to 70$^\circ C$

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Minimum</th>
<th>Typical</th>
<th>Maximum</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{DD}$</td>
<td>Power Supply Voltage</td>
<td></td>
<td>2.375</td>
<td>2.5</td>
<td>2.625</td>
<td>V</td>
</tr>
<tr>
<td>$V_{DDO}$</td>
<td>Output Supply Voltage</td>
<td></td>
<td>1.6</td>
<td>1.8</td>
<td>2.0</td>
<td>V</td>
</tr>
<tr>
<td>$I_{DD}$</td>
<td>Power Supply Current</td>
<td>ENABLE [1:2] = 00</td>
<td></td>
<td></td>
<td>8</td>
<td>mA</td>
</tr>
<tr>
<td>$I_{DDO}$</td>
<td>Output Supply Current</td>
<td>ENABLE [1:2] = 00</td>
<td></td>
<td></td>
<td>3</td>
<td>mA</td>
</tr>
</tbody>
</table>
### Table 4G. LVC莫斯/LVTTL DC Characteristics, $T_A = 0°C$ to $70°C$

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Minimum</th>
<th>Typical</th>
<th>Maximum</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{IH}$</td>
<td>Input High Voltage ENABLE1, ENABLE2</td>
<td>$V_{DD} = 3.3V \pm 5%$</td>
<td>2</td>
<td></td>
<td>$V_{DD} + 0.3$</td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{DD} = 2.5V \pm 5%$</td>
<td>1.7</td>
<td>$V_{DD} + 0.3$</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{DD} = 1.8V \pm 0.2V$</td>
<td>0.65 * $V_{DD}$</td>
<td></td>
<td>$V_{DD} + 0.3$</td>
<td>V</td>
</tr>
<tr>
<td>$V_{IL}$</td>
<td>Input Low Voltage ENABLE1, ENABLE2</td>
<td>$V_{DD} = 3.3V \pm 5%$</td>
<td>-0.3</td>
<td>0.8</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{DD} = 2.5V \pm 5%$</td>
<td>-0.3</td>
<td>0.7</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{DD} = 1.8V \pm 0.2V$</td>
<td>-0.3</td>
<td>0.35 * $V_{DD}$</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$V_{OH}$</td>
<td>Output High Voltage</td>
<td>$V_{DD} = 3.3V \pm 5%$; NOTE 1</td>
<td>2.6</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{DD} = 2.5V \pm 5%$; $I_{OH} = -1mA$</td>
<td>2.0</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{DD} = 2.5V \pm 5%$; NOTE 1</td>
<td>1.8</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{DD} = 1.8V \pm 0.2V$; NOTE 1</td>
<td>$V_{DD} - 0.3$</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>$V_{OL}$</td>
<td>Output Low Voltage; NOTE 1</td>
<td>$V_{DD} = 3.3V \pm 5%$; NOTE 1</td>
<td>0.5</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{DD} = 2.5V \pm 5%$; $I_{OL} = 1mA$</td>
<td>0.4</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{DD} = 2.5V \pm 5%$; NOTE 1</td>
<td>0.45</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{DD} = 1.8V \pm 0.2V$; NOTE 1</td>
<td>0.35</td>
<td></td>
<td></td>
<td>V</td>
</tr>
</tbody>
</table>

NOTE 1: Outputs terminated with 50Ω to $V_{DD}/2$. See Parameter Measurement Information, Output Load Test Circuit diagrams.

### Table 5. Crystal Characteristics

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Minimum</th>
<th>Typical</th>
<th>Maximum</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>Mode of Oscillation</td>
<td></td>
<td>Fundamental</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Frequency</td>
<td></td>
<td>10</td>
<td>40</td>
<td></td>
<td>MHz</td>
</tr>
<tr>
<td>Equivalent Series Resistance (ESR)</td>
<td></td>
<td>50</td>
<td></td>
<td></td>
<td>Ω</td>
</tr>
<tr>
<td>Shunt Capacitance</td>
<td></td>
<td>7</td>
<td></td>
<td></td>
<td>pF</td>
</tr>
<tr>
<td>Drive Level</td>
<td></td>
<td>1</td>
<td></td>
<td></td>
<td>mW</td>
</tr>
</tbody>
</table>
## AC Electrical Characteristics

**Table 6A. AC Characteristics, \( V_{DD} = V_{DDO} = 3.3\text{V} \pm 5\%, T_A = 0°C \) to 70°C**

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Minimum</th>
<th>Typical</th>
<th>Maximum</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>( f_{\text{MAX}} )</td>
<td>Output Frequency</td>
<td>Using External Crystal</td>
<td>10</td>
<td>40</td>
<td></td>
<td>MHz</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Using External Clock</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>Source NOTE 1</td>
<td>DC</td>
<td>100</td>
<td></td>
<td>MHz</td>
</tr>
<tr>
<td>( t_{\text{sk(o)}} )</td>
<td>Output Skew; NOTE 2, 3</td>
<td></td>
<td></td>
<td>80</td>
<td></td>
<td>ps</td>
</tr>
<tr>
<td>( t_{\text{jit}} )</td>
<td>RMS Phase Jitter (Random); NOTE 4</td>
<td>25MHz, Integration Range: 100Hz – 1MHz</td>
<td></td>
<td>0.13</td>
<td></td>
<td>ps</td>
</tr>
<tr>
<td>( t_R / t_F )</td>
<td>Output Rise/Fall Time</td>
<td>20% to 80%</td>
<td>200</td>
<td>800</td>
<td></td>
<td>ps</td>
</tr>
<tr>
<td>( odc )</td>
<td>Output Duty Cycle</td>
<td></td>
<td>48</td>
<td>52</td>
<td></td>
<td>%</td>
</tr>
<tr>
<td>( t_{\text{EN}} )</td>
<td>Output Enable Time; NOTE 5</td>
<td>ENABLE1</td>
<td></td>
<td></td>
<td></td>
<td>cycles</td>
</tr>
<tr>
<td></td>
<td></td>
<td>ENABLE2</td>
<td></td>
<td></td>
<td></td>
<td>cycles</td>
</tr>
<tr>
<td>( t_{\text{DIS}} )</td>
<td>Output Disable Time; NOTE 5</td>
<td>ENABLE1</td>
<td></td>
<td></td>
<td></td>
<td>cycles</td>
</tr>
<tr>
<td></td>
<td></td>
<td>ENABLE2</td>
<td></td>
<td></td>
<td></td>
<td>cycles</td>
</tr>
</tbody>
</table>

**NOTE:** Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lpfm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

All parameters measured at \( f \leq f_{\text{MAX}} \) using a crystal input unless noted otherwise.

Terminated at 50Ω to \( V_{DDO}/2 \).

NOTE 1: \( \text{XTAL\_IN} \) can be overdriven by a single-ended LVCMOS signal. Please refer to Application Information section.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at \( V_{DDO}/2 \).

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 4: See phase noise plot.

NOTE 5: These parameters are guaranteed by characterization. Not tested in production.

**Table 6B. AC Characteristics, \( V_{DD} = V_{DDO} = 2.5\text{V} \pm 5\%, T_A = 0°C \) to 70°C**

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Minimum</th>
<th>Typical</th>
<th>Maximum</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>( f_{\text{MAX}} )</td>
<td>Output Frequency</td>
<td>Using External Crystal</td>
<td>10</td>
<td>40</td>
<td></td>
<td>MHz</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Using External Clock</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>Source NOTE 1</td>
<td>DC</td>
<td>100</td>
<td></td>
<td>MHz</td>
</tr>
<tr>
<td>( t_{\text{sk(o)}} )</td>
<td>Output Skew; NOTE 2, 3</td>
<td></td>
<td></td>
<td>80</td>
<td></td>
<td>ps</td>
</tr>
<tr>
<td>( t_{\text{jit}} )</td>
<td>RMS Phase Jitter (Random); NOTE 4</td>
<td>25MHz, Integration Range: 100Hz – 1MHz</td>
<td></td>
<td>0.26</td>
<td></td>
<td>ps</td>
</tr>
<tr>
<td>( t_R / t_F )</td>
<td>Output Rise/Fall Time</td>
<td>20% to 80%</td>
<td>200</td>
<td>800</td>
<td></td>
<td>ps</td>
</tr>
<tr>
<td>( odc )</td>
<td>Output Duty Cycle</td>
<td></td>
<td>47</td>
<td>53</td>
<td></td>
<td>%</td>
</tr>
<tr>
<td>( t_{\text{EN}} )</td>
<td>Output Enable Time; NOTE 5</td>
<td>ENABLE1</td>
<td></td>
<td></td>
<td></td>
<td>cycles</td>
</tr>
<tr>
<td></td>
<td></td>
<td>ENABLE2</td>
<td></td>
<td></td>
<td></td>
<td>cycles</td>
</tr>
<tr>
<td>( t_{\text{DIS}} )</td>
<td>Output Disable Time; NOTE 5</td>
<td>ENABLE1</td>
<td></td>
<td></td>
<td></td>
<td>cycles</td>
</tr>
<tr>
<td></td>
<td></td>
<td>ENABLE2</td>
<td></td>
<td></td>
<td></td>
<td>cycles</td>
</tr>
</tbody>
</table>

**NOTE:** Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lpfm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

All parameters measured at \( f \leq f_{\text{MAX}} \) using a crystal input unless noted otherwise.

Terminated at 50Ω to \( V_{DDO}/2 \).

NOTE 1: \( \text{XTAL\_IN} \) can be overdriven by a single-ended LVCMOS signal. Please refer to Application Information section.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at \( V_{DDO}/2 \).

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 4: See phase noise plot.

NOTE 5: These parameters are guaranteed by characterization. Not tested in production.
### Table 6C. AC Characteristics, $V_{DD} = V_{DDO} = 1.8V \pm 0.2V$, $T_A = 0°C$ to $70°C$

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Minimum</th>
<th>Typical</th>
<th>Maximum</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>$f_{MAX}$</td>
<td>Output Frequency</td>
<td>Using External Crystal</td>
<td>10 MHz</td>
<td>40 MHz</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>Using External Clock Source NOTE 1</td>
<td>DC</td>
<td>100 MHz</td>
<td></td>
<td></td>
</tr>
<tr>
<td>$f_{sk(o)}$</td>
<td>Output Skew; NOTE 2, 3</td>
<td></td>
<td>80 ps</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$t_{jit(Ø)}$</td>
<td>RMS Phase Jitter (Random)</td>
<td>25MHz, Integration Range: 100Hz – 1MHz</td>
<td>0.27 ps</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$t_{R} / t_{F}$</td>
<td>Output Rise/Fall Time</td>
<td>20% to 80%</td>
<td>200 ps</td>
<td>900 ps</td>
<td></td>
<td></td>
</tr>
<tr>
<td>$t_{dc}$</td>
<td>Output Duty Cycle</td>
<td></td>
<td>47 %</td>
<td>53 %</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

All parameters measured at $f \leq f_{MAX}$ using a crystal input unless noted otherwise.

Terminated at 50Ω to $V_{DDO}/2$.

NOTE 1: XTAL_IN can be overdriven by a single-ended LVCMOS signal. Please refer to Application Information section.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at $V_{DDO}/2$.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 4: These parameters are guaranteed by characterization. Not tested in production.

### Table 6D. AC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, $T_A = 0°C$ to $70°C$

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Minimum</th>
<th>Typical</th>
<th>Maximum</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>$f_{MAX}$</td>
<td>Output Frequency</td>
<td>Using External Crystal</td>
<td>10 MHz</td>
<td>40 MHz</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>Using External Clock Source NOTE 1</td>
<td>DC</td>
<td>100 MHz</td>
<td></td>
<td></td>
</tr>
<tr>
<td>$f_{sk(o)}$</td>
<td>Output Skew; NOTE 2, 3</td>
<td></td>
<td>80 ps</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$t_{jit(Ø)}$</td>
<td>RMS Phase Jitter (Random)</td>
<td>25MHz, Integration Range: 100Hz – 1MHz</td>
<td>0.14 ps</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$t_{R} / t_{F}$</td>
<td>Output Rise/Fall Time</td>
<td>20% to 80%</td>
<td>200 ps</td>
<td>800 ps</td>
<td></td>
<td></td>
</tr>
<tr>
<td>$t_{dc}$</td>
<td>Output Duty Cycle</td>
<td></td>
<td>48 %</td>
<td>52 %</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

All parameters measured at $f \leq f_{MAX}$ using a crystal input unless noted otherwise.

Terminated at 50Ω to $V_{DDO}/2$.

NOTE 1: XTAL_IN can be overdriven by a single-ended LVCMOS signal. Please refer to Application Information section.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at $V_{DDO}/2$.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 4: These parameters are guaranteed by characterization. Not tested in production.
Table 6E. AC Characteristics, \(V_{DD} = 3.3V \pm 5\%, \ V_{DDO} = 1.8V \pm 0.2V, \ T_A = 0^\circ C \) to 70°C

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Minimum</th>
<th>Typical</th>
<th>Maximum</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>f_{MAX}</td>
<td>Output Frequency</td>
<td>Using External Crystal</td>
<td>10</td>
<td>40</td>
<td>100</td>
<td>MHz</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Using External Clock</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>Source NOTE 1</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>t_{sk}</td>
<td>Output Skew; NOTE 2, 3</td>
<td></td>
<td>80</td>
<td></td>
<td></td>
<td>ps</td>
</tr>
<tr>
<td>t jit</td>
<td>RMS Phase Jitter (Random)</td>
<td>25MHz, Integration Range:</td>
<td>0.18</td>
<td></td>
<td></td>
<td>ps</td>
</tr>
<tr>
<td>t_{R}</td>
<td>Output Rise/Fall Time</td>
<td>20% to 80%</td>
<td>200</td>
<td>900</td>
<td></td>
<td>ps</td>
</tr>
<tr>
<td>odc</td>
<td>Output Duty Cycle</td>
<td></td>
<td>48</td>
<td>52</td>
<td></td>
<td>%</td>
</tr>
<tr>
<td>t_{EN}</td>
<td>Output Enable Time; NOTE 4</td>
<td>ENABLE1</td>
<td>4</td>
<td>4</td>
<td></td>
<td>cycles</td>
</tr>
<tr>
<td></td>
<td></td>
<td>ENABLE2</td>
<td>4</td>
<td>4</td>
<td></td>
<td>cycles</td>
</tr>
<tr>
<td>t_{DIS}</td>
<td>Output Disable Time; NOTE 4</td>
<td>ENABLE1</td>
<td>4</td>
<td>4</td>
<td></td>
<td>cycles</td>
</tr>
<tr>
<td></td>
<td></td>
<td>ENABLE2</td>
<td>4</td>
<td>4</td>
<td></td>
<td>cycles</td>
</tr>
</tbody>
</table>

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

All parameters measured at \(f \leq f_{MAX}\) using a crystal input unless noted otherwise.

Terminated at 50\(\Omega\) to \(V_{DDO}/2\).

NOTE 1: XTAL_IN can be overdriven by a single-ended LVCMOS signal. Please refer to Application Information section.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at \(V_{DDO}/2\).

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 4: These parameters are guaranteed by characterization. Not tested in production.

Table 6F. AC Characteristics, \(V_{DD} = 2.5V \pm 5\%, \ V_{DDO} = 1.8V \pm 0.2V, \ T_A = 0^\circ C \) to 70°C

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Minimum</th>
<th>Typical</th>
<th>Maximum</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>f_{MAX}</td>
<td>Output Frequency</td>
<td>Using External Crystal</td>
<td>10</td>
<td>40</td>
<td>100</td>
<td>MHz</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Using External Clock</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>Source NOTE 1</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>t_{sk}</td>
<td>Output Skew; NOTE 2, 3</td>
<td></td>
<td>80</td>
<td></td>
<td></td>
<td>ps</td>
</tr>
<tr>
<td>t jit</td>
<td>RMS Phase Jitter (Random)</td>
<td>25MHz, Integration Range:</td>
<td>0.19</td>
<td></td>
<td></td>
<td>ps</td>
</tr>
<tr>
<td>t_{R}</td>
<td>Output Rise/Fall Time</td>
<td>20% to 80%</td>
<td>200</td>
<td>900</td>
<td></td>
<td>ps</td>
</tr>
<tr>
<td>odc</td>
<td>Output Duty Cycle</td>
<td></td>
<td>47</td>
<td>53</td>
<td></td>
<td>%</td>
</tr>
<tr>
<td>t_{EN}</td>
<td>Output Enable Time; NOTE 4</td>
<td>ENABLE1</td>
<td>4</td>
<td>4</td>
<td></td>
<td>cycles</td>
</tr>
<tr>
<td></td>
<td></td>
<td>ENABLE2</td>
<td>4</td>
<td>4</td>
<td></td>
<td>cycles</td>
</tr>
<tr>
<td>t_{DIS}</td>
<td>Output Disable Time; NOTE 4</td>
<td>ENABLE1</td>
<td>4</td>
<td>4</td>
<td></td>
<td>cycles</td>
</tr>
<tr>
<td></td>
<td></td>
<td>ENABLE2</td>
<td>4</td>
<td>4</td>
<td></td>
<td>cycles</td>
</tr>
</tbody>
</table>

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

All parameters measured at \(f \leq f_{MAX}\) using a crystal input unless noted otherwise.

Terminated at 50\(\Omega\) to \(V_{DDO}/2\).

NOTE 1: XTAL_IN can be overdriven by a single-ended LVCMOS signal. Please refer to Application Information section.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at \(V_{DDO}/2\).

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 4: These parameters are guaranteed by characterization. Not tested in production.
Typical Phase Noise at 25MHz (2.5V Core/2.5V Output)

RMS Phase Jitter (Random)
100Hz to 1MHz = 0.26ps (typical)
Parameter Measurement Information

1. 3.3V Core/3.3V LVCMOS Output Load AC Test Circuit

2. 2.5V Core/2.5V LVCMOS Output Load AC Test Circuit

3. 1.8V Core/1.8V LVCMOS Output Load AC Test Circuit

4. 3.3V Core/2.5V LVCMOS Output Load AC Test Circuit

5. 3.3V Core/1.8V LVCMOS Output Load AC Test Circuit

6. 2.5V Core/1.8V LVCMOS Output Load AC Test Circuit
Parameter Measurement Information, continued

Output Skew

Output Duty Cycle/Pulse Width/Period

Output Rise/Fall Time
Application Information

Crystal Input Interface

Figure 2 shows an example of 83905 crystal interface with a parallel resonant crystal. The frequency accuracy can be fine tuned by adjusting the C1 and C2 values. For a parallel crystal with loading capacitance CL = 18pF, to start with, we suggest C1 = 15pF and C2 = 15pF. These values may be slightly fine tuned further to optimize the frequency accuracy for different board layouts. Slightly increasing the C1 and C2 values will slightly reduce the frequency. Slightly decreasing the C1 and C2 values will slightly increase the frequency. For the oscillator circuit below, R1 can be used, but is not required. For new designs, it is recommended that R1 not be used.

![Figure 2. Crystal Input Interface](image)

LVCMOS to XTAL Interface

The XTAL_IN input can accept a single-ended LVCMOS signal through an AC coupling capacitor. A general interface diagram is shown in Figure 3. The XTAL_OUT pin can be left floating. The input edge rate can be as slow as 10ns. For LVCMOS inputs, it is recommended that the amplitude be reduced from full swing to half swing in order to prevent signal interference with the power rail and to reduce noise. This configuration requires that the output impedance of the driver (Ro) plus the series resistance (Rs) equals the transmission line impedance. In addition, matched termination at the crystal input will attenuate the signal in half. This can be done in one of two ways. First, R1 and R2 in parallel should equal the transmission line impedance. For most 50Ω applications, R1 and R2 can be 100Ω. This can also be accomplished by removing R1 and making R2 50Ω. By overdriving the crystal oscillator, the device will be functional, but note, the device performance is guaranteed by using a quartz crystal.

![Figure 3. General Diagram for LVCMOS Driver to XTAL Input Interface](image)
VFQFN EPAD Thermal Release Path

In order to maximize both the removal of heat from the package and the electrical performance, a land pattern must be incorporated on the Printed Circuit Board (PCB) within the footprint of the package corresponding to the exposed metal pad or exposed heat slug on the package, as shown in Figure 4. The solderable area on the PCB, as defined by the solder mask, should be at least the same size/shape as the exposed pad/slug area on the package to maximize the thermal/electrical performance. Sufficient clearance should be designed on the PCB between the outer edges of the land pattern and the inner edges of pad pattern for the leads to avoid any shorts.

While the land pattern on the PCB provides a means of heat transfer and electrical grounding from the package to the board through a solder joint, thermal vias are necessary to effectively conduct from the surface of the PCB to the ground plane(s). The land pattern must be connected to ground through these vias. The vias act as “heat pipes”. The number of vias (i.e. “heat pipes”) are application specific and dependent upon the package power dissipation as well as electrical conductivity requirements. Thus, thermal and electrical analysis and/or testing are recommended to determine the minimum number needed. Maximum thermal and electrical performance is achieved when an array of vias is incorporated in the land pattern. It is recommended to use as many vias connected to ground as possible. It is also recommended that the via diameter should be 12 to 13mil (0.30 to 0.33mm) with 1oz copper via barrel plating. This is desirable to avoid any solder wicking inside the via during the soldering process which may result in voids in solder between the exposed pad/slug and the thermal land. Precautions should be taken to eliminate any solder voids between the exposed heat slug and the land pattern. Note: These recommendations are to be used as a guideline only. For further information, please refer to the Application Note on the Surface Mount Assembly of Amkor’s Thermally/Electrically Enhance Leadframe Base Package, Amkor Technology.

Figure 4. P.C. Assembly for Exposed Pad Thermal Release Path – Side View (drawing not to scale)

Recommendations for Unused Input and Output Pins

Inputs:
LVCMOS Control Pins
All control pins have internal pull-ups or pull-downs; additional resistance is not required but can be added for additional protection. A 1kΩ resistor can be used.

Outputs:
LVCMOS Outputs
All unused LVCMOS output can be left floating. There should be no trace attached.
Layout Guideline

Figure 5 shows an example of 83905 application schematic. The schematic example focuses on functional connections and is not configuration specific. In this example, the device is operated at $V_{DD} = 3.3\,\text{V}$ and $V_{DDO} = 1.8\,\text{V}$. The crystal inputs are loaded with an 18pf load resonant quartz crystal. The tuning capacitors (C1, C2) are fairly accurate, but minor adjustments might be required. Refer to the pin description and functional tables in the datasheet to ensure the logic control inputs are properly set. For the LVCMOS output drivers, two termination examples are shown in the schematic. For additional termination examples are shown in the LVCMOS Termination Application Note.

As with any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. The 83905 provides separate $V_{DD}$ and $V_{DDO}$ power supplies to isolate any high switching noise from coupling into the internal oscillator. In order to achieve the best possible filtering, it is highly recommended that the 0.1µF capacitors on the device side of the ferrite beads be placed on the device side of the PCB as close to the power pins as possible. This is represented by the placement of these capacitors in the schematic. If space is limited, the ferrite beads, 10µF and 0.1µF capacitor connected to the board supplies can be placed on the opposite side of the PCB. If space permits, place all filter components on the device side of the board.

Power supply filter recommendations are a general guideline to be used for reducing external noise from coupling into the devices. The filter performance is designed for a wide range of noise frequencies. This low-pass filter starts to attenuate noise at approximately 0kHz. If a specific frequency noise component is known, such as switching power supplies frequencies, it is recommended that component values be adjusted and if required, additional filtering be added. Additionally, good general design practices for power plane voltage stability suggests adding bulk capacitance in the local area of all devices.

![Figure 5. Schematic of Recommended Layout](image)

Figure 5. Schematic of Recommended Layout
Power Considerations

This section provides information on power dissipation and junction temperature for the 83905. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the 83905 is the sum of the core power plus the analog power plus the power dissipated due to the load. The following is the power dissipation for \( V_{DD} = 3.3V + 5\% = 3.465V \), which gives worst case results.

- \( \text{Power (core)MAX} = V_{DD,MAX} \times (I_{DD} + I_{DDO}) = 3.465V \times (10mA + 5mA) = 51.9mW \)
- \( \text{Output Impedance} R_{OUT} \text{ Power Dissipation due to Loading} 50\Omega \text{ to } V_{DD}/2 \)
  \( \text{Output Current} I_{OUT} = V_{DD,MAX} / [2 \times (50\Omega + R_{OUT})] = 3.465V / [2 \times (50\Omega + 7\Omega)] = 30.4mA \)
- Power Dissipation on the \( R_{OUT} \) per LVCMOS output
  \( \text{Power} (R_{OUT}) = R_{OUT} \times (I_{OUT})^2 = 7\Omega \times (30.4mA)^2 = 6.5mW \text{ per output} \)
- Total Power Dissipation on the \( R_{OUT} \)
  \( \text{Total Power} (R_{OUT}) = 6.5mW \times 6 = 39mW \)

Dynamic Power Dissipation at 25MHz

\( \text{Power} (25MHz) = C_{PD} \times \text{Frequency} \times (V_{DD})^2 = 19pF \times 25MHz \times (3.465V)^2 = 5.70mW \text{ per output} \)
\( \text{Total Power} (25MHz) = 5.70mW \times 6 = 34.2mW \)

Total Power Dissipation

\[ \text{Total Power} = \text{Power (core)MAX} + \text{Total Power} (R_{OUT}) + \text{Total Power} (25MHz) = 51.98mW + 39mW + 34.2mW = 125.1mW \]

2. Junction Temperature.

Junction temperature, \( T_j \), is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature is 125°C.

The equation for \( T_j \) is as follows: \( T_j = \theta_{JA} \times P_d\_total + T_A \)

\( T_j = \text{Junction Temperature} \)
\( \theta_{JA} = \text{Junction-to-Ambient Thermal Resistance} \)
\( P_d\_total = \text{Total Device Power Dissipation} \) (example calculation is in section 1 above)
\( T_A = \text{Ambient Temperature} \)

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance \( \theta_{JA} \) must be used. Assuming no air flow and a multi-layer board, the appropriate value is 100.3°C/W per Table 7 below.

Therefore, \( T_j \) for an ambient temperature of 70°C with all outputs switching is:

\[ 70\degree C + 0.125W \times 100.3\degree C/W = 82.5\degree C \]

This is below the limit of 125°C.

This calculation is only an example. \( T_j \) will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (multi-layer).

<table>
<thead>
<tr>
<th>( \theta_{JA} ) by Velocity</th>
<th>0</th>
<th>1</th>
<th>2.5</th>
</tr>
</thead>
<tbody>
<tr>
<td>Meters per Second</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Multi-Layer PCB, JEDEC Standard Test Boards</td>
<td>100.3°C/W</td>
<td>96.0°C/W</td>
<td>93.9°C/W</td>
</tr>
</tbody>
</table>

Table 7. Thermal Resistance \( \theta_{JA} \) for 16-Lead TSSOP, Forced Convection
Reliability Information

Table 8A. $\theta_{JA}$ vs. Air Flow Table for a 16-Lead TSSOP

<table>
<thead>
<tr>
<th>$\theta_{JA}$ vs. Air Flow</th>
<th>0</th>
<th>1</th>
<th>2.5</th>
</tr>
</thead>
<tbody>
<tr>
<td>Meters per Second</td>
<td>100.3°C/W</td>
<td>96.0°C/W</td>
<td>93.9°C/W</td>
</tr>
<tr>
<td>Multi-Layer PCB, JEDEC Standard Test Boards</td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

Table 8B. $\theta_{JA}$ vs. Air Flow Table for a 16-Lead SOIC

<table>
<thead>
<tr>
<th>$\theta_{JA}$ vs. Air Flow</th>
<th>0</th>
<th>1</th>
<th>2.5</th>
</tr>
</thead>
<tbody>
<tr>
<td>Meters per Second</td>
<td>78.8°C/W</td>
<td>71.1°C/W</td>
<td>66.2°C/W</td>
</tr>
<tr>
<td>Multi-Layer PCB, JEDEC Standard Test Boards</td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

Table 8C. $\theta_{JA}$ vs. Air Flow Table for a 20-Lead VFQFN

<table>
<thead>
<tr>
<th>$\theta_{JA}$ vs. Air Flow</th>
<th>0</th>
<th>1</th>
<th>2.5</th>
</tr>
</thead>
<tbody>
<tr>
<td>Meters per Second</td>
<td>57.5°C/W</td>
<td>50.3°C/W</td>
<td>45.1°C/W</td>
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<td>Multi-Layer PCB, JEDEC Standard Test Boards</td>
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<td></td>
<td></td>
</tr>
</tbody>
</table>

Transistor Count

The transistor count for 83905: 339
### Package Outline and Package Dimensions

#### Package Outline - G Suffix for 16-Lead TSSOP

![Diagram of 16-Lead TSSOP Package Outline]

#### Package Outline - M Suffix for 16-Lead SOIC

![Diagram of 16-Lead SOIC Package Outline]

### Table 9A. Package Dimensions for 16-Lead TSSOP

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Minimum</th>
<th>Maximum</th>
</tr>
</thead>
<tbody>
<tr>
<td>N</td>
<td>16</td>
<td></td>
</tr>
<tr>
<td>A</td>
<td>1.20</td>
<td></td>
</tr>
<tr>
<td>A1</td>
<td>0.05</td>
<td>0.15</td>
</tr>
<tr>
<td>A2</td>
<td>0.80</td>
<td>1.05</td>
</tr>
<tr>
<td>b</td>
<td>0.19</td>
<td>0.30</td>
</tr>
<tr>
<td>c</td>
<td>0.09</td>
<td>0.20</td>
</tr>
<tr>
<td>D</td>
<td>4.90</td>
<td>5.10</td>
</tr>
<tr>
<td>E</td>
<td>6.40 Basic</td>
<td></td>
</tr>
<tr>
<td>E1</td>
<td>4.30</td>
<td>4.50</td>
</tr>
<tr>
<td>e</td>
<td>0.65 Basic</td>
<td></td>
</tr>
<tr>
<td>L</td>
<td>0.45</td>
<td>0.75</td>
</tr>
<tr>
<td>α</td>
<td>0°</td>
<td>8°</td>
</tr>
<tr>
<td>aaaa</td>
<td>0.10</td>
<td></td>
</tr>
</tbody>
</table>

Reference Document: JEDEC Publication 95, MO-153

### Table 9B. Package Dimensions for 16-Lead SOIC

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Minimum</th>
<th>Maximum</th>
</tr>
</thead>
<tbody>
<tr>
<td>N</td>
<td>16</td>
<td></td>
</tr>
<tr>
<td>A</td>
<td>1.35</td>
<td>1.75</td>
</tr>
<tr>
<td>A1</td>
<td>0.10</td>
<td>0.25</td>
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<tr>
<td>B</td>
<td>0.33</td>
<td>0.51</td>
</tr>
<tr>
<td>C</td>
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<td>0.25</td>
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<tr>
<td>D</td>
<td>9.80</td>
<td>10.00</td>
</tr>
<tr>
<td>E</td>
<td>3.80</td>
<td>4.00</td>
</tr>
<tr>
<td>e</td>
<td>1.27 Basic</td>
<td></td>
</tr>
<tr>
<td>H</td>
<td>5.80</td>
<td>6.20</td>
</tr>
<tr>
<td>h</td>
<td>0.25</td>
<td>0.50</td>
</tr>
<tr>
<td>L</td>
<td>0.40</td>
<td>1.27</td>
</tr>
<tr>
<td>α</td>
<td>0°</td>
<td>8°</td>
</tr>
</tbody>
</table>

Reference Document: JEDEC Publication 95, MS-012
Package Outline and Package Dimensions

Package Outline - K Suffix for 20-Lead VFQFN

Table 10. Package Dimensions

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Minimum</th>
<th>Nominal</th>
<th>Maximum</th>
</tr>
</thead>
<tbody>
<tr>
<td>N</td>
<td></td>
<td>20</td>
<td></td>
</tr>
<tr>
<td>A</td>
<td>0.80</td>
<td>1.00</td>
<td></td>
</tr>
<tr>
<td>A1</td>
<td>0</td>
<td>0.05</td>
<td></td>
</tr>
<tr>
<td>A3</td>
<td>0.2 Ref.</td>
<td></td>
<td></td>
</tr>
<tr>
<td>b</td>
<td>0.20</td>
<td>0.25</td>
<td>0.30</td>
</tr>
<tr>
<td>N_D &amp; N_E</td>
<td>0.20</td>
<td>0.25</td>
<td>0.30</td>
</tr>
<tr>
<td>D &amp; E</td>
<td>4.00 Basic</td>
<td></td>
<td></td>
</tr>
<tr>
<td>D2 &amp; E2</td>
<td>1.95</td>
<td>2.25</td>
<td></td>
</tr>
<tr>
<td>e</td>
<td>0.50 Basic</td>
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<td></td>
</tr>
<tr>
<td>L</td>
<td>0.45</td>
<td>0.55</td>
<td>0.65</td>
</tr>
</tbody>
</table>

NOTE:

The drawing and dimension data originate from IDT package outline drawing PSC-4170, rev03.

1. Dimensions and tolerances conform to ASME Y14.5M-1994
2. All dimensions are in millimeters. All angles are in degrees.
3. N is the total number of terminals.
4. All specifications comply with JEDEC MO-220.

Reference Document: JEDEC Publication 95, MO-220
# Ordering Information

## Table 11. Ordering Information

<table>
<thead>
<tr>
<th>Part/Order Number</th>
<th>Marking</th>
<th>Package</th>
<th>Shipping Packaging</th>
<th>Temperature</th>
</tr>
</thead>
<tbody>
<tr>
<td>83905AMLF</td>
<td>83905AML</td>
<td>“Lead-Free” 16-Lead SOIC</td>
<td>Tube</td>
<td>0°C to 70°C</td>
</tr>
<tr>
<td>83905AMLFT</td>
<td>83905AML</td>
<td>“Lead-Free” 16-Lead SOIC</td>
<td>Tape &amp; Reel</td>
<td>0°C to 70°C</td>
</tr>
<tr>
<td>83905AGLF</td>
<td>83905AGL</td>
<td>“Lead-Free” 16-Lead TSSOP</td>
<td>Tube</td>
<td>0°C to 70°C</td>
</tr>
<tr>
<td>83905AGLFT</td>
<td>83905AGL</td>
<td>“Lead-Free” 16-Lead TSSOP</td>
<td>Tape &amp; Reel</td>
<td>0°C to 70°C</td>
</tr>
<tr>
<td>83905AKLF</td>
<td>3905AL</td>
<td>“Lead-Free” 20-Lead VFQFN</td>
<td>Tray</td>
<td>0°C to 70°C</td>
</tr>
<tr>
<td>83905AKLFT</td>
<td>3905AL</td>
<td>“Lead-Free” 20-Lead VFQFN</td>
<td>Tape &amp; Reel</td>
<td>0°C to 70°C</td>
</tr>
</tbody>
</table>
## Revision History Sheet

<table>
<thead>
<tr>
<th>Rev</th>
<th>Table</th>
<th>Page</th>
<th>Description of Change</th>
<th>Date</th>
</tr>
</thead>
<tbody>
<tr>
<td>A</td>
<td></td>
<td>2</td>
<td>Added Enable Timing Diagram.</td>
<td>3/28/05</td>
</tr>
<tr>
<td>B</td>
<td>T6A - T6F</td>
<td>1</td>
<td>Features Section - added RMS Phase Jitter bullet.</td>
<td>4/8/05</td>
</tr>
<tr>
<td></td>
<td></td>
<td>5 - 7</td>
<td>AC Characteristics Tables - added RMS Phase Jitter specs.</td>
<td>4/8/05</td>
</tr>
<tr>
<td></td>
<td></td>
<td>8</td>
<td>Added Phase Noise Plot.</td>
<td>4/8/05</td>
</tr>
<tr>
<td>B</td>
<td>T9</td>
<td>14</td>
<td>Ordering Information Table - added TSSOP, non-LF part number.</td>
<td>4/25/05</td>
</tr>
<tr>
<td>B</td>
<td></td>
<td>11</td>
<td>Added Crystal Input Interface in Application Section.</td>
<td>5/16/05</td>
</tr>
<tr>
<td></td>
<td></td>
<td>12</td>
<td>Added Schematic layout.</td>
<td>5/16/05</td>
</tr>
<tr>
<td>B</td>
<td></td>
<td>3</td>
<td>Absolute Maximum Ratings - corrected 20-Lead VFQFN package Thermal Impedance.</td>
<td>10/2/06</td>
</tr>
<tr>
<td></td>
<td></td>
<td>11</td>
<td>Added Recommendations for Unused Input and Output Pins.</td>
<td>10/2/06</td>
</tr>
<tr>
<td></td>
<td></td>
<td>13</td>
<td>Corrected Theta JA Air Flow Table for 20-Lead VFQFN.</td>
<td>10/2/06</td>
</tr>
<tr>
<td>B</td>
<td>T9</td>
<td>11</td>
<td>Added LVCOS to XTAL Interface section.</td>
<td>7/9/07</td>
</tr>
<tr>
<td></td>
<td></td>
<td>12</td>
<td>Added Thermal Release Path section.</td>
<td>7/9/07</td>
</tr>
<tr>
<td></td>
<td></td>
<td>17</td>
<td>AC Characteristics Table - added lead-free marking for 20-Lead VFQFN package.</td>
<td>7/9/07</td>
</tr>
<tr>
<td>B</td>
<td>T7B - T7C</td>
<td>3</td>
<td>Absolute Maximum Ratings - updated TSSOP and VFQFN Thermal Impedance.</td>
<td>1/24/08</td>
</tr>
<tr>
<td></td>
<td></td>
<td>12</td>
<td>Updated Thermal Release Path section.</td>
<td>1/24/08</td>
</tr>
<tr>
<td></td>
<td></td>
<td>14</td>
<td>Updated TSSOP and VFQFN Thermal Impedance.</td>
<td>1/24/08</td>
</tr>
<tr>
<td></td>
<td></td>
<td>16</td>
<td>Added note to VFQFN Package Outline.</td>
<td>1/24/08</td>
</tr>
<tr>
<td>B</td>
<td></td>
<td>15</td>
<td>Added Power Considerations section.</td>
<td>7/20/09</td>
</tr>
<tr>
<td></td>
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<td>Converted datasheet format.</td>
<td>7/20/09</td>
</tr>
<tr>
<td>B</td>
<td>T10</td>
<td>19</td>
<td>Removed leaded order-able parts from Ordering Information table</td>
<td>11/14/12</td>
</tr>
<tr>
<td>C</td>
<td>T6D</td>
<td>1, 15</td>
<td>Deleted HiPerClockS references. Features, last bullet: updated packaging note.</td>
<td>4/18/13</td>
</tr>
<tr>
<td></td>
<td></td>
<td>1</td>
<td>Mixed AC Characteristics Table - corrected typo, switched Output Rise/Fall Time spec with Output Duty Cycle spec.</td>
<td>4/18/13</td>
</tr>
<tr>
<td></td>
<td>T9A</td>
<td>14</td>
<td>Replaced schematic.</td>
<td>4/18/13</td>
</tr>
<tr>
<td></td>
<td></td>
<td>17</td>
<td>16-Lead TSSOP Package Table - corrected dimension A1 Minimum = 0.05.</td>
<td>4/18/13</td>
</tr>
<tr>
<td></td>
<td></td>
<td>18</td>
<td>Updated VFQFN package outline page.</td>
<td>4/18/13</td>
</tr>
<tr>
<td></td>
<td>T11</td>
<td>19</td>
<td>Ordering Information table - deleted Lead-free note, and quantity from Tape and Reel.</td>
<td>4/18/13</td>
</tr>
<tr>
<td>C</td>
<td></td>
<td>1</td>
<td>Pin Assignment: Corrected 20-Lead illustration cut-off text</td>
<td>2/27/14</td>
</tr>
<tr>
<td>C</td>
<td>T6A - T6F</td>
<td>1</td>
<td>Pin Assignment, 20-Lead VFQFN: removed the Epad dimensions.</td>
<td>8/6/14</td>
</tr>
<tr>
<td></td>
<td></td>
<td>6 - 8</td>
<td>Changed NOTE 1 to XTAL_IN can be overdriven by a single-ended LVCMOS signal. Please refer to Application Information section.</td>
<td>8/6/14</td>
</tr>
<tr>
<td></td>
<td>T10</td>
<td>9</td>
<td>Deleted 3.3V Phase Noise Plot</td>
<td>8/6/14</td>
</tr>
<tr>
<td></td>
<td></td>
<td>11</td>
<td>Deleted RMS Phase Jitter graph.</td>
<td>8/6/14</td>
</tr>
<tr>
<td></td>
<td></td>
<td>18</td>
<td>Modified dimensions to reflect tightened tolerances.</td>
<td>8/6/14</td>
</tr>
<tr>
<td></td>
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<td>21</td>
<td>Updated contact information.</td>
<td>8/6/14</td>
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<tr>
<td>D</td>
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<td>2</td>
<td>Figure 1 corrected.</td>
<td>9/27/16</td>
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<td>Updated datasheet header/footer.</td>
<td>9/27/16</td>
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<td>Deleted “ICS” prefix from part number throughout the datasheet</td>
<td>9/27/16</td>
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